

HD74AC365

Hex Buffer/Driver with 3-State Output

REJ03D0269-0200Z
 (Previous ADE-205-390 (Z))
 Rev.2.00
 Jul.16.2004

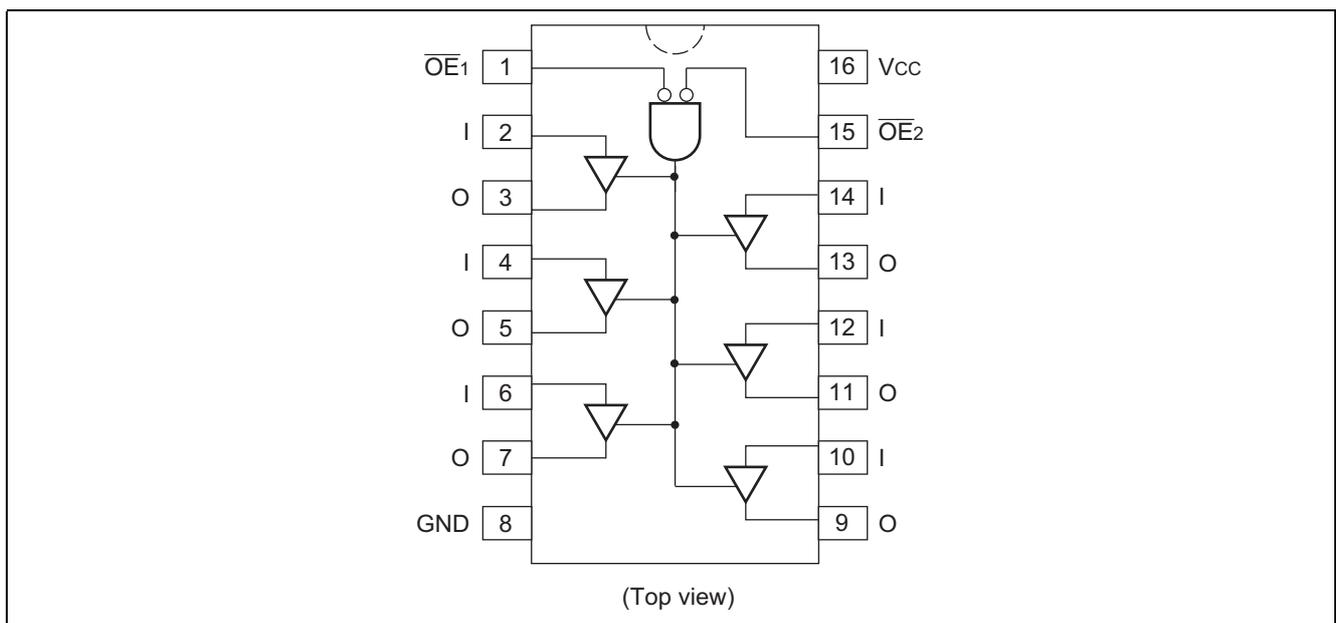
Features

- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Outputs Source/Sink 24 mA
- Ordering Information

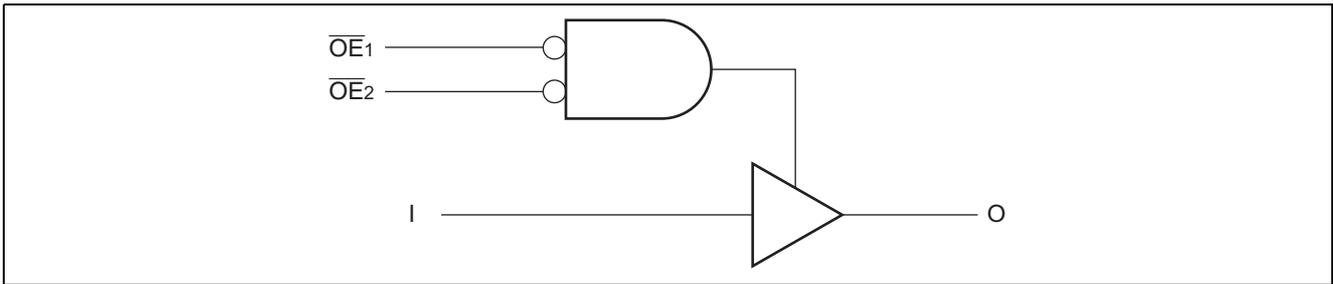
Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74AC365FPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74AC365RPEL	SOP-16 pin (JEDEC)	FP-16DNV	RP	EL (2,500 pcs/reel)

Notes: 1. Please consult the sales office for the above package availability.
 2. The packages with lead-free pins are distinguished from the conventional products by adding V at the end of the package code.

Pin Arrangement



Logic Symbol



Pin Names

- $\overline{OE}_1, \overline{OE}_2$ 3-State Output: Enable Input (Active Low)
- I Inputs
- O Outputs

Truth Table

Inputs			Output
\overline{OE}_1	\overline{OE}_2	I	O
L	L	L	L
L	L	H	H
X	H	X	Z
H	X	X	Z

- H : High Voltage Level
- L : Low Voltage Level
- X : Immaterial
- Z : High Impedance

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V_{CC}	-0.5 to 7	V	
DC input diode current	I_{IK}	-20	mA	$V_I = -0.5V$
		20	mA	$V_I = V_{CC}+0.5V$
DC input voltage	V_I	-0.5 to $V_{CC}+0.5$	V	
DC output diode current	I_{OK}	-50	mA	$V_O = -0.5V$
		50	mA	$V_O = V_{CC}+0.5V$
DC output voltage	V_O	-0.5 to $V_{CC}+0.5$	V	
DC output source or sink current	I_O	± 50	mA	
DC V_{CC} or ground current per output pin	I_{CC}, I_{GND}	± 50	mA	
Storage temperature	Tstg	-65 to +150	°C	

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V_{CC}	2 to 6	V	
Input and Output voltage	V_I, V_O	0 to V_{CC}	V	
Operating temperature	Ta	-40 to +85	°C	
Input rise and fall time (except Schmitt inputs) V_{IN} 30% to 70% V_{CC}	tr, tf	8	ns/V	$V_{CC} = 3.0V$
				$V_{CC} = 4.5 V$
				$V_{CC} = 5.5 V$

DC Characteristics

Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Condition		
			min.	typ.	max.	min.	max.				
Input Voltage	V _{IH}	3.0	2.1	1.5	—	2.1	—	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V		
		4.5	3.15	2.25	—	3.15	—				
		5.5	3.85	2.75	—	3.85	—				
	V _{IL}	3.0	—	1.50	0.9	—	0.9		V _{OUT} = 0.1 V or V _{CC} - 0.1 V		
		4.5	—	2.25	1.35	—	1.35				
		5.5	—	2.75	1.65	—	1.65				
Output voltage	V _{OH}	3.0	2.9	2.99	—	2.9	—	V	V _{IN} = V _{IL} or V _{IH} I _{OUT} = -50 μA		
		4.5	4.4	4.49	—	4.4	—				
		5.5	5.4	5.49	—	5.4	—				
		3.0	2.58	—	—	2.48	—			V _{IN} = V _{IL} or V _{IH}	I _{OH} = -12 mA
		4.5	3.94	—	—	3.80	—				I _{OH} = -24 mA
		5.5	4.94	—	—	4.80	—				I _{OH} = -24 mA
	V _{OL}	3.0	—	0.002	0.1	—	0.1	V	V _{IN} = V _{IL} or V _{IH} I _{OUT} = 50 μA		
		4.5	—	0.001	0.1	—	0.1				
		5.5	—	0.001	0.1	—	0.1				
		3.0	—	—	0.32	—	0.37			V _{IN} = V _{IL} or V _{IH}	I _{OL} = 12 mA
		4.5	—	—	0.32	—	0.37				I _{OL} = 24 mA
		5.5	—	—	0.32	—	0.37				I _{OL} = 24 mA
	Input leakage current	I _{IN}	5.5	—	—	±0.1	—	±1.0	μA	V _{IN} = V _{CC} or GND	
	3 State current	I _{OZ}	5.5	—	—	±0.5	—	±5.0	μA	V _{IN(OE)} = V _{IL} , V _{IH} V _{IN} = V _{CC} or GND V _{OUT} = V _{CC} or GND	
	Dynamic output current*	I _{OLD}	5.5	—	—	—	86	—	mA	V _{OLD} = 1.1 V	
I _{OHD}		5.5	—	—	—	-75	—	mA	V _{OHD} = 3.85 V		
Quiescent supply current	I _{CC}	5.5	—	—	8.0	—	80	μA	V _{IN} = V _{CC} or ground		

*Maximum test duration 2.0 ms, one output loaded at a time.

AC Characteristics

Item	Symbol	V _{CC} (V)* ¹	Ta = +25°C C _L = 50 pF			Ta = -40°C to +85°C C _L = 50 pF		Unit
			Min	Typ	Max	Min	Max	
Propagation delay	t _{PLH}	3.3	1.0	7.0	9.0	1.0	10.0	ns
		5.0	1.0	5.0	7.0	1.0	7.5	
Propagation delay	t _{PHL}	3.3	1.0	7.0	9.0	1.0	10.0	ns
		5.0	1.0	5.0	7.0	1.0	7.5	
Enable time	t _{ZH}	3.3	1.0	9.0	12.5	1.0	13.0	ns
		5.0	1.0	7.0	9.5	1.0	10.0	
Enable time	t _{ZL}	3.3	1.0	10.0	12.5	1.0	13.5	ns
		5.0	1.0	8.0	10.0	1.0	10.5	
Disable time	t _{HZ}	3.3	1.0	9.5	12.0	1.0	12.5	ns
		5.0	1.0	7.5	10.0	1.0	10.5	
Disable time	t _{LZ}	3.3	1.0	9.0	12.5	1.0	13.5	ns
		5.0	1.0	7.0	10.0	1.0	10.5	

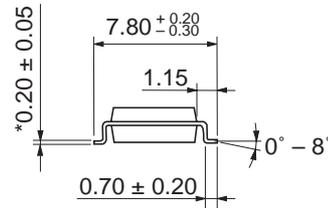
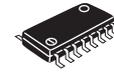
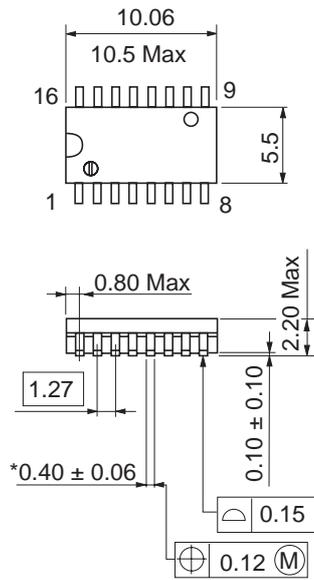
Note: 1. Voltage Range 3.3 is 3.3 V ± 0.3 V
Voltage Range 5.0 is 5.0 V ± 0.5 V

Capacitance

Item	Symbol	Typ	Unit	Condition
Input capacitance	C_{IN}	4.5	pF	$V_{CC} = 5.5 \text{ V}$
Power dissipation capacitance	C_{PD}	45.0	pF	$V_{CC} = 5.0 \text{ V}$

Package Dimensions

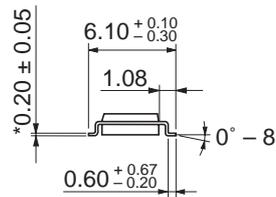
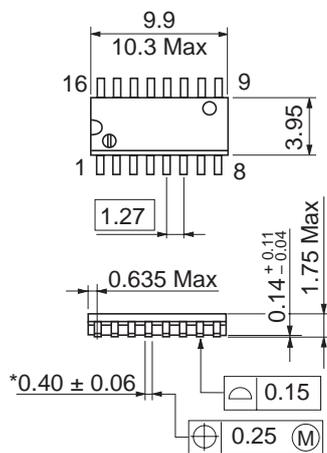
As of January, 2003
Unit: mm



*Ni/Pd/Au plating

Package Code	FP-16DAV
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.24 g

As of January, 2003
Unit: mm



*Ni/Pd/Au plating

Package Code	FP-16DNV
JEDEC	Conforms
JEITA	Conforms
Mass (reference value)	0.15 g

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Tel: <44> (1628) 585 100, Fax: <44> (1628) 585 900

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